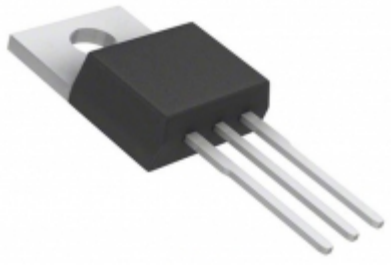
	<h2 style="color: red;">FQP13N10L</h2>
	<p>Hersteller-Teilenummer: FQP13N10L</p> <p>Hersteller / Marke: Fairchild/ON Semiconductor</p> <p>Teil der Beschreibung: MOSFET N-CH 100V 12.8A TO-220</p> <p>Datenblätter: 1.FQP13N10L.pdf 2.FQP13N10L.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 77361 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	FQP13N10L
Hersteller	Fairchild/ON Semiconductor
Beschreibung	MOSFET N-CH 100V 12.8A TO-220
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	77361 pcs Stock
Serie	QFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 175°C (TJ)
Befestigungsart	Through Hole
Verpackung / Gehäuse	TO-220-3
Supplier Device-Gehäuse	TO-220-3
Verlustleistung (max)	65W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	100V
Strom - Ununterbrochener Abfluss (Id) bei 25 °C	12.8A (Tc)
Rds On (Max) @ Id, Vgs	180 mOhm @ 6.4A, 10V
VGS (th) (Max) @ Id	2V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	12nC @ 5V
Eingabekapazität (Ciss) (Max) @ Vds	520pF @ 25V
Antriebsspannung (Max Rds On, Min Rds On)	5V, 10V
Vgs (Max)	±20V
Verpackung	Tube

FQP13N10L ist neu im Original, Suche FQP13N10L Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie FQP13N10L Fairchild/ON Semiconductor mit Garantie und Vertrauen. Anfrage FQP13N10L: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>FQP13N50C Fairchild/ON Semiconductor MOSFET N-CH 500V 13A TO-220</p>	 <p>FQP13N50 Fairchild/ON Semiconductor MOSFET N-CH 500V 12.5A TO-220</p>	 <p>FQP13N10C FSC FQP13N10C FSC</p>	 <p>FQP13N06L FQP13N06 Original FQP13N06L FQP13N06 Original</p>
 <p>FQP13N50C_F105 AMI Semiconductor / ON Semiconductor IC POWER MANAGEMENT</p>	 <p>FQP13N10 Fairchild/ON Semiconductor MOSFET N-CH 100V 12.8A TO-220</p>	 <p>FQP13N10 AMI Semiconductor / ON Semiconductor MOSFET N-CH 100V 12.8A TO-220</p>	 <p>FQP13N50 AMI Semiconductor / ON Semiconductor MOSFET N-CH 500V 12.5A TO-220</p>

heiße Teile

Mehr

⊗ FQP11N40C	↔ FQP11N50CF	⇒ FQP11N50CF	D FQP11N60	⇒ FQP11N60C
⊣ FQP11N65C	⊗ FQP11P06	D FQP11P06	⇒ FQP12N20	⇒ FQP12N60
⊗ FQP12N60	⊣ FQP12N60C	⊗ FQP12N60C	↔ FQP12N65C	⇒ FQP12P10
D FQP12P10	⊗ FQP12P20	⊣ FQP12P20	⊗ FQP13N06	⇒ FQP13N06
⇒ FQP13N06L	↔ FQP13N06L	⊗ FQP13N10	⊣ FQP13N10	⇒ FQP13N10L
↔ FQP13N50	⇒ FQP13N50	D FQP13N50C	⊗ FQP13N50C	⊣ FQP13N60C
⊗ FQP140N03	D FQP140N03L	⇒ FQP14N15	↔ FQP14N15	⇒ FQP14N30
⊣ FQP14N30	⊗ FQP14N80	↔ FQP14N80C	⇒ FQP15N16	⇒ FQP15N30
⊗ FQP15N50	⊣ FQP15N60	⊗ FQP15N65	D FQP15N80	⇒ FQP15P12
↔ FQP15P12	⊗ FQP16N15	⊣ FQP16N15	⊗ FQP16N25	⇒ FQP16N25

Contact us: Info@Y-IC.com

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